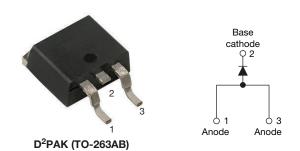


RoHS

COMPLIANT HALOGEN

**FREE** 

# High Voltage Surface Mount Input Rectifier Diode, 10 A



### **LINKS TO ADDITIONAL RESOURCES**



PRIMARY CHARACTERISTICS							
I <sub>F(AV)</sub> 10 A							
$V_R$	1200 V						
V <sub>F</sub> at I <sub>F</sub>	1.1 V						
I <sub>FSM</sub>	160 A						
T <sub>J</sub> max.	150 °C						
Package	D <sup>2</sup> PAK (TO-263AB)						
Circuit configuration	Single						

#### **FEATURES**

- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Glass passivated pellet chip junction
- AEC-Q101 qualified
- Meets JESD 201 class 1A whisker test
- Flexible solution for reliable AC power rectification
- High surge, low V<sub>F</sub> rugged blocking diode for DC charging stations
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **APPLICATIONS**

- · Input rectification
- On-board and off-board EV / HEV battery chargers

#### **DESCRIPTION**

The VS-10ETS12SLHM3 rectifier series has been optimized for very low forward voltage drop, with moderate leakage.

OUTPUT CURRENT IN TYPICAL APPLICATIONS								
APPLICATIONS	SINGLE-PHASE BRIDGE	THREE-PHASE BRIDGE	UNITS					
Capacitive input filter T <sub>A</sub> = 55 °C, T <sub>J</sub> = 125 °C common heatsink of 1 °C/W	12.0	16.0	А					

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I <sub>F(AV)</sub>	Sinusoidal waveform	10	A						
V <sub>RRM</sub>		1200	V						
I <sub>FSM</sub>		160	A						
$V_{F}$	10 A, T <sub>J</sub> = 25 °C	1.1	V						
T <sub>J</sub>		-40 to +150	°C						

VOLTAGE RATINGS								
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA					
VS-10ETS12SLHM3	1200	1300	0.5					



ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum average forward current	I <sub>F(AV)</sub>	$T_C = 105$ °C, 180° conduction half sine wave	10					
Maximum peak one cycle non-repetitive surge current	I <sub>FSM</sub>	10 ms sine pulse, rated V <sub>RRM</sub> applied	135	Α				
		10 ms sine pulse, no voltage reapplied	160					
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	91	A <sup>2</sup> s				
Maximum 1-t for fusing		10 ms sine pulse, no voltage reapplied	130 A-S					
Maximum I <sup>2</sup> √t for fusing	I²√t	t = 0.1 ms to 10 ms, no voltage reapplied	1290	A²√s				

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST (	CONDITIONS	VALUES	UNITS		
Maximum forward voltage drop	$V_{FM}$	10 A, T <sub>J</sub> = 25 °C	1.1	V			
Forward slope resistance	r <sub>t</sub>	T <sub>.1</sub> = 150 °C	20	$m\Omega$			
Threshold voltage	V <sub>F(TO)</sub>	1J = 150 C	0.82	V			
Maximum reverse leakage current	1	T <sub>J</sub> = 25 °C	V <sub>R</sub> = rated V <sub>RRM</sub>	0.05	mA		
Maximum reverse leakage current	IRM	T <sub>J</sub> = 150 °C	VR = Ialeu VRRM	0.50	IIIA		

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C			
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation	2.5	°C/W			
Maximum thermal resistance, junction to ambient (PCB mount)	R <sub>thJA</sub> <sup>(1)</sup>		62	C/VV			
Approximate weight			2	g			
Approximate weight			0.07	OZ.			
Marking device		Case style D <sup>2</sup> PAK (TO-263AB)	10ETS	12SH			

### Note

 $<sup>^{(1)}</sup>$  When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140  $\mu m$ ) copper 40 °C/W.



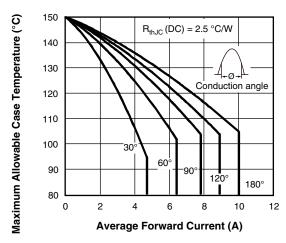


Fig. 1 - Current Rating Characteristics

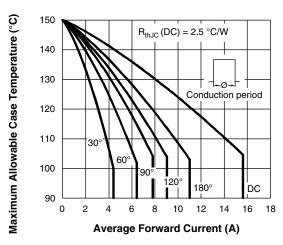


Fig. 2 - Current Rating Characteristics

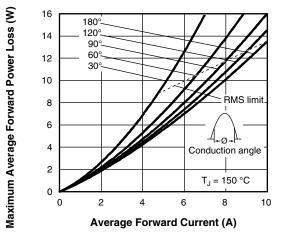


Fig. 3 - Forward Power Loss Characteristics

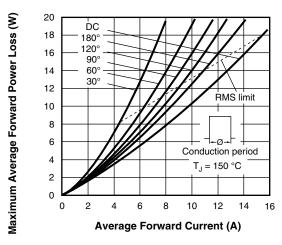


Fig. 4 - Forward Power Loss Characteristics

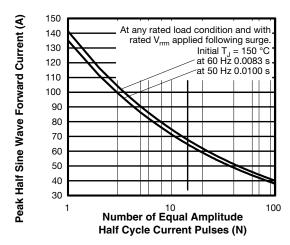


Fig. 5 - Maximum Non-Repetitive Surge Current

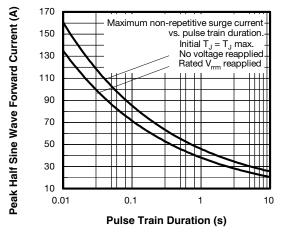


Fig. 6 - Maximum Non-Repetitive Surge Current

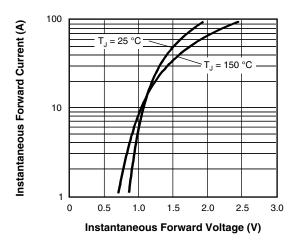


Fig. 7 - Forward Voltage Drop Characteristics

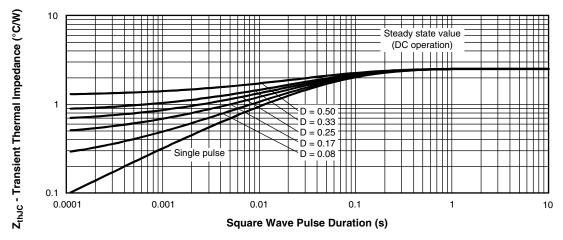
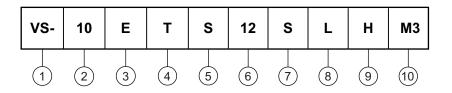


Fig. 8 - Thermal Impedance  $Z_{thJC}$  Characteristics



## **ORDERING INFORMATION TABLE**





Vishay Semicondutors product

2 - Current rating (10 = 10 A)

Circuit configuration:

E = single

4 - Package:

 $T = D^2PAK (TO-263AB)$ 

5 - Type of silicon:

S = standard recovery rectifier

7 - S = surface mountable

 L = tape and reel (left oriented), for different orientation, contact factory

9 - H = AEC-Q101 qualified

10 - Environmental digit:

M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

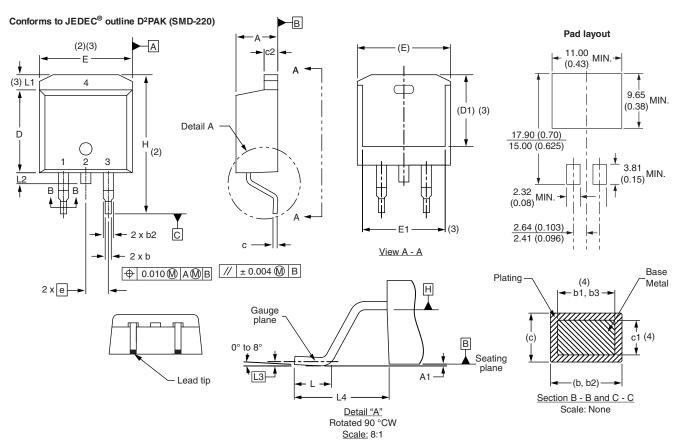
ORDERING INFORMATION (Example)							
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPT							
VS-10ETS12SLHM3	800	800	13" diameter reel				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95046				
Part marking information	www.vishay.com/doc?95444				
Packaging information	www.vishay.com/doc?96317				
SPICE model	www.vishay.com/doc?97334				



## D<sup>2</sup>PAK

### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIM	ETERS	INC	INCHES		NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES	NOTES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	) BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB

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